

Title of Change:	NCL2801 Datasheet Correction for Vcc, hyst (C and D Versions)				
Effective date:	7 September 2019				
Contact information:	Contact your local ON Semiconductor Sales Office or <marquita.jones@onsemi.com></marquita.jones@onsemi.com>				
Type of notification:	This Product Bulletin is for notification purposes only. ON Semiconductor will proceed with implementation of this change upon publication of this Product Bulletin.				
Change Category:	Wafer Fab Assembly Change		Test Change	✓ Other	Datasheet Change
Change Sub-Category(s): Manufacturing Site Addition Manufacturing Site Transfer Manufacturing Process Change 	Product specific change Shipping/Packaging/Ma				-
Sites Affected:	ON Semiconductor Sites: None		External Foundry/Subcon Sites: None		
Description and Purpose: The product datasheet has been up typographical error. There has been	en no change in product n	nanufacturing, die desig	n, or bill of material.		
Vcc hyst (C& D Versions)		Min	Ту		Max
Before the change		3.3 V	3.6	i V	3.9 V
After the change		1.25 V	2.5	V	3.75 V
List of Affected Parts: Note: Only the standard (off the sh specific PCN addendum in the PCN	•••		•	d by this PCN are	shown in the custome

NCL2801CDADR2G NCL2801CDBDR2G D

Product	Customer Part Number	
NCL2801CDADR2G		
NCL2801CDBDR2G		